

DESCRIPTION

The SPN8910 is the N-Channel logic enhancement mode power field effect transistor which is produced using super high cell density DMOS trench technology. The SPN8910 has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low RDS(ON) and fast switching speed.

Load Switch

MB/NB/VGA

APPLICATIONS

FEATURES

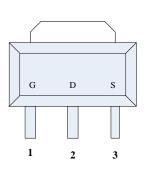
- 100V/2A, RDS(ON)= $310m\Omega@VGS=10V$
- ♦ High density cell design for extremely low RDS (ON)
- ◆ Exceptional on-resistance and maximum DC current capability
- ◆ SOT-89 package design

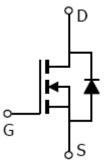
PIN CONFIGURATION

SOT-89

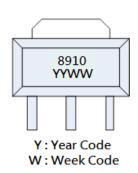
High Frequency Small Power Switching for

Network DC/DC Power System





PART MARKING



PIN DESCRIPTION					
Pin	Symbol	Description			
1	G	Gate			
2	D	Drain			
3	S	Source			

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN8910S89RGB	SOT-89	SPN8910
SPN8910S89TGB	SOT-89	SPN8910

※ SPN8910S89RGB : Tape Reel ; Pb − Free ; Halogen - Free

※ SPN8910S89RGB : Tube ; Pb − Free ; Halogen - Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter			Symbol	Typical	Unit
Drain-Source Voltage		Vdss	100	V	
Gate –Source Voltage		VGSS	±20	V	
Continuous Drain Current(T _J =150°C)		ΓA=25°C	ID	2.2	٨
		Га=70°С		1.7	A
Pulsed Drain Current			Ірм	5.5	A
Power Dissipation	Ta=25°C		PD	1.5	W
Operating Junction Temperature		nperature		150	°C
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	85	°C/W	

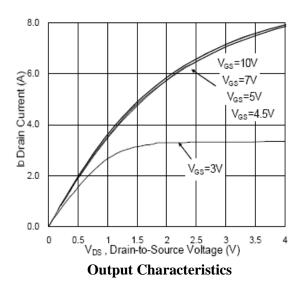
ELECTRICAL CHARACTERISTICS

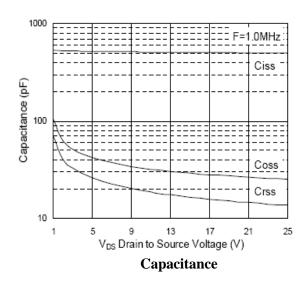
(TA=25°C Unless otherwise noted)

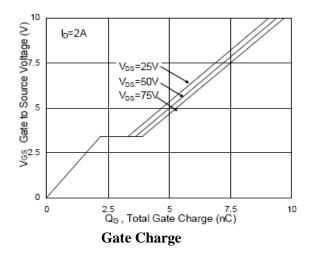
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	100			17	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	1	1.5	2.5	V	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA	
		VDS=80V,VGS=0V			1	uA	
Zero Gate Voltage Drain Current	Idss	V _{DS} =80V,V _{GS} =0V T _J =125°C			5		
On-State Drain Current	ID(on)	Vds≥5V,Vgs =10V	2.2			A	
Drain-Source On-Resistance	RDS(on)	VGS= 10V,ID=2A		0.26	0.31	Ω	
Diani-Source On-Resistance	KDS(on)	$V_{GS}=4.5V_{ID}=1A$		0.27	0.32	Ω	
Forward Transconductance	gfs	Vds=5V,Id=2A		2.4		S	
Diode Forward Voltage	Vsd	Is=1A,VGS =0V			1.2	V	
Dynamic							
Total Gate Charge	Qg			9	13	nC	
Gate-Source Charge	Qgs	V _{DS} =50V,V _{GS} =10V I _D = 2A		2			
Gate-Drain Charge	Qgd			1.4			
Input Capacitance	Ciss			508		pF	
Output Capacitance	Coss	VDS=15V,VGS=0V f=1MHz		29			
Reverse Transfer Capacitance	Crss			16.5		-	
Turn-On Time	td(on)			2		nS	
	tr	VDD=50V, ID=2A,		21.5			
T.,,,,, Off Time	td(off)	VGEN=10V, RG= 3.3Ω		11.2			
Turn-Off Time	tf			18.8			

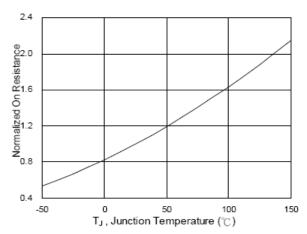


TYPICAL CHARACTERISTICS





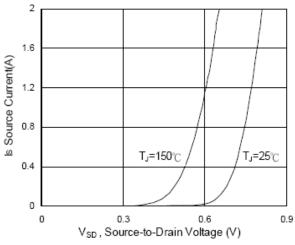




On-Resistance vs. Junction Temperature



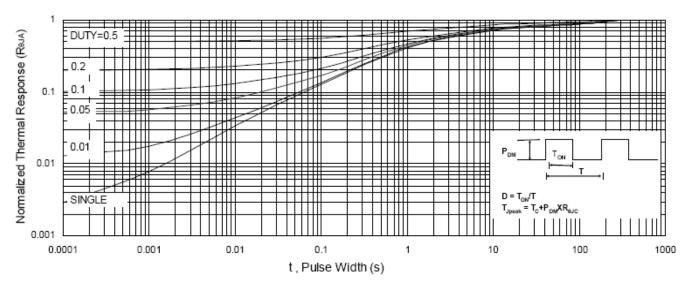
TYPICAL CHARACTERISTICS



260 (GE) 255 250 250 245 2 4 6 8 10

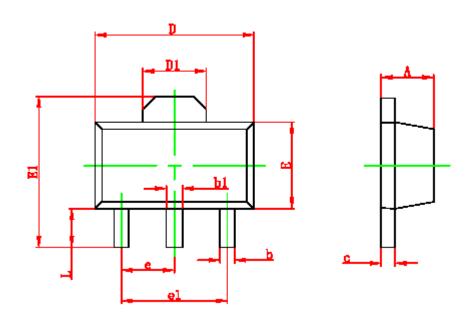
Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-Source Voltage



Normalized Thermal Transient Impedance, Junction to Foot

SOT-89 PACKAGE OUTLINE



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550 REF.		0.061 REF.		
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP.		0.060 TYP.		
e1	3.000 TYP.		3.000 TYP. 0.118 TYP.		TYP.
L	0.900	1.200	0.035	0.047	

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